



## APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

<b>Title of Invention</b>	METHOD OF FORMING STRAINED SILICON ON INSULATOR		
Application Type : regular, utility Attorney Docket Number : YOR920000707US2			
Correspondence address: Customer Number: 27127 			
<b>Inventor Information:</b>  <u>Inventor 1:</u> <b>Applicant Authority Type:</b> Inventor <b>Citizenship:</b> US <b>Name prefix:</b> Mr. <b>Given Name:</b> Kern <b>Family Name:</b> Rim <b>Residence:</b> <b>City of Residence:</b> Yorktown Heights <b>State of Residence:</b> NY <b>Country of Residence:</b> US <b>Address-1 of Mailing Address:</b> 2095 Van Cortlandt Circle <b>Address-2 of Mailing Address:</b> <b>City of Mailing Address:</b> Yorktown Heights <b>State of Mailing Address:</b> NY <b>Postal Code of Mailing Address:</b> 10598 <b>Country of Mailing Address:</b> US <b>Phone:</b> <b>Fax:</b> <b>E-mail:</b>			
<b>Attorney Information:</b>  practitioner(s) at Customer Number: 27127   as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.			

Assignee 1:

<b>Organization Name:</b>	International Business Machines
<b>Address-1 of Mailing Address:</b>	Old Orchard Road
<b>Address-2 of Mailing Address:</b>	
<b>City of Mailing Address:</b>	Armonk
<b>State of Mailing Address:</b>	NY
<b>Postal Code of Mailing Address:</b>	10504
<b>Country of Mailing Address:</b>	US
<b>Phone:</b>	
<b>Fax:</b>	
<b>E-mail:</b>	